74HC366; 74HCT366 Hex buffer/line driver; 3-state; inverting

Rev. 4 — 4 September 2012

1. General description

The 74HC366; 74HCT366 is a hex inverter/line driver with 3-state outputs controlled by the output enable inputs ($\overline{OE1}$). A HIGH on \overline{OEn} causes the outputs to assume a high impedance OFF-state. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC}.

The 74HC366; 74HCT366 is functionally identical to:

• 74HC365; 74HCT365, but has inverted outputs

2. Features and benefits

- Inverting outputs
- Input levels:
 - For 74HC366: CMOS level
 - For 74HC366: TTL level
- Complies with JEDEC standard no. 7A
- ESD protection:
 - HBM EIA/JESD22-A114-F exceeds 2000 V
 - MM EIA/JESD22-A115-A exceeds 200 V
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Multiple package options

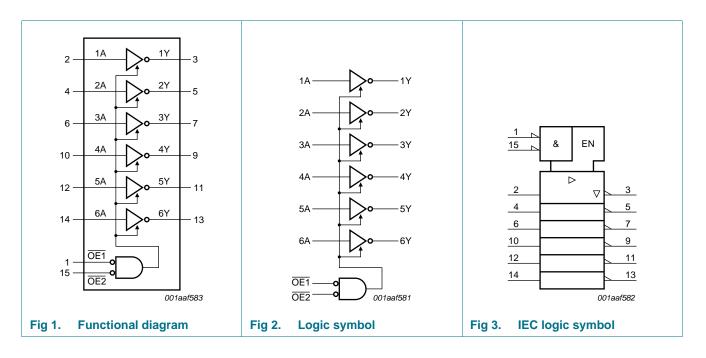


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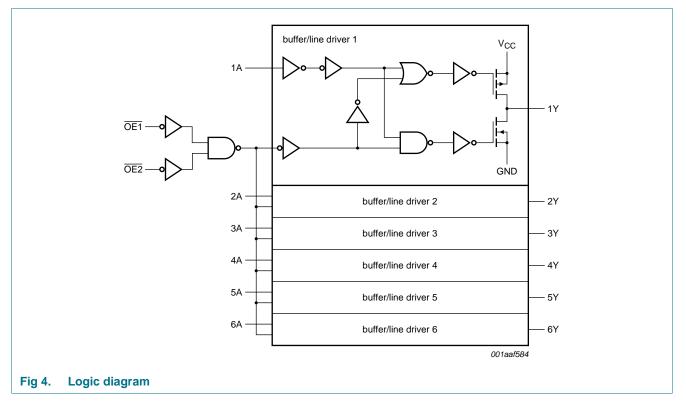
3. Ordering information

Packaga								
Fachage	Package							
Temperature range	Name	Description	Version					
–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1					
–40 °C to +125 °C	DIP16	plastic dual in-line package; 16 leads (300 mil); long body	SOT38-1					
–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1					
–40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1					
–40 °C to +125 °C	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1					
–40 °C to +125 °C	DIP16	plastic dual in-line package; 16 leads (300 mil); long body	SOT38-1					
–40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1					
	-40 °C to +125 °C -40 °C to +125 °C	-40 °C to +125 °C SO16 -40 °C to +125 °C DIP16 -40 °C to +125 °C TSSOP16 -40 °C to +125 °C SO16 -40 °C to +125 °C SSOP16 -40 °C to +125 °C DIP16	-40 °C to +125 °CSO16plastic small outline package; 16 leads; body width 3.9 mm-40 °C to +125 °CDIP16plastic dual in-line package; 16 leads (300 mil); long body-40 °C to +125 °CTSSOP16plastic thin shrink small outline package; 16 leads; body width 4.4 mm-40 °C to +125 °CSO16plastic small outline package; 16 leads; body width 3.9 mm-40 °C to +125 °CSO16plastic small outline package; 16 leads; body width 3.9 mm-40 °C to +125 °CSSOP16plastic shrink small outline package; 16 leads; body width 5.3 mm-40 °C to +125 °CDIP16plastic dual in-line package; 16 leads (300 mil); long body-40 °C to +125 °CTSSOP16plastic dual in-line package; 16 leads (300 mil); long body					

4. Functional diagram

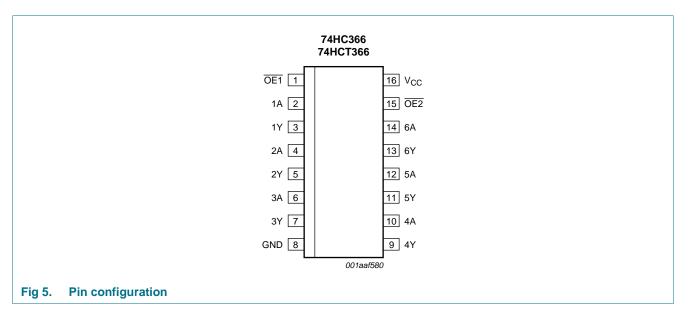


Hex buffer/line driver; 3-state; inverting



Pinning information 5.

5.1 Pinning



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5.2 Pin description

Table 2.	Pin description	
Symbol	Pin	Description
OE1	1	output enable input 1 (active LOW)
1A	2	data input 1
1Y	3	data output 1
2A	4	data input 2
2Y	5	data output 2
ЗA	6	data input 3
3Y	7	data output 3
GND	8	ground (0 V)
4Y	9	data output 4
4A	10	data input 4
5Y	11	data output 5
5A	12	data input 5
6Y	13	data output 6
6A	14	data input 6
OE2	15	output enable input 2 (active LOW)
V _{CC}	16	supply voltage

6. Functional description

Table 3. Function table^[1]

Control		Input	Output
OE1	OE2	nA	nY
L	L	L	Н
L	L	Н	L
X	Н	Х	Z
Н	Х	Х	Z

[1] H = HIGH voltage level;

L = LOW voltage level;

X = don't care;

Z = high-impedance OFF-state.

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7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+7	V
I _{IK}	input clamping current	$V_{I} < -0.5$ V or $V_{I} > V_{CC}$ + 0.5 V	-	±20	mA
I _{OK}	output clamping current	V_O < –0.5 V or V_O > V_{CC} + 0.5 V	-	±20	mA
lo	output current	$V_{O} = -0.5 \text{ V to} (V_{CC} + 0.5 \text{ V})$	-	±35	mA
I _{CC}	supply current		-	70	mA
I _{GND}	ground current		-	-70	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	DIP16 package	<u>[1]</u> _	750	mW
		SO16 package	[2] _	500	mW
		SSOP16 package	[3]	500	mW
		TSSOP16 package	<u>[3]</u>	500	mW

[1] For DIP16 packages: P_{tot} derates linearly with 12 mW/K above 70 $^\circ\text{C}.$

[2] For SO16 packages: P_{tot} derates linearly with 8 mW/K above 70 $^\circ\text{C}.$

[3] For SSOP16 and TSSOP16 packages: Ptot derates linearly with 5.5 mW/K above 60 °C.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V)

Symbol	Parameter	Conditions		74HC366	3	7	4HCT36	6	Unit
			Min	Тур	Max	Min	Тур	Max	
V _{CC}	supply voltage		2.0	5.0	6.0	4.5	5.0	5.5	V
VI	input voltage		0	-	V_{CC}	0	-	V_{CC}	V
Vo	output voltage		0	-	V_{CC}	0	-	V_{CC}	V
T _{amb}	ambient temperature		-40	+25	+125	-40	+25	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	$V_{CC} = 2.0 V$	-	-	625	-	-	-	ns/V
		$V_{CC} = 4.5 V$	-	1.67	139	-	1.67	139	ns/V
		$V_{CC} = 6.0 V$	-	-	83	-	-	-	ns/V

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9. Static characteristics

Table 6. Static characteristics 74HC366

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Uni
T _{amb} = 2	5 °C					
VIH	HIGH-level input voltage	$V_{CC} = 2.0 V$	1.5	1.2	-	V
		$V_{CC} = 4.5 V$	3.15	2.4	-	V
		$V_{CC} = 6.0 V$	4.2	3.2	-	V
VIL	LOW-level input voltage	$V_{CC} = 2.0 V$	-	0.8	0.5	V
		$V_{CC} = 4.5 V$	-	2.1	1.35	V
		$V_{CC} = 6.0 V$	-	2.8	1.8	V
√ _{ОН}	HIGH-level output voltage	$V_I = V_{IH} \text{ or } V_{IL}$	-	-	-	
		$I_{O} = -20 \ \mu\text{A}; \ V_{CC} = 2.0 \ \text{V}$	1.9	2.0	-	V
		$I_{O} = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ V$	4.4	4.5	-	V
		$I_{O} = -20 \ \mu\text{A}; \ V_{CC} = 6.0 \ V$	5.9	6.0	-	V
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	V
		$I_{O} = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_0 = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	0	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	0	0.1	V
		$I_0 = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	0	0.1	V
		$I_{O} = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	V
		$I_{O} = 7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	V
1	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	μΑ
loz	OFF-state output current	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{O} = V_{CC} \text{ or } GND; V_{CC} = 6.0 \text{ V}$	-	-	±0.5	μA
lcc	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0$ V	-	-	8.0	μA
Cı	input capacitance		-	3.5	-	pF
T _{amb} = –	40 °C to +85 °C					
VIH	HIGH-level input voltage	$V_{CC} = 2.0 V$	1.5	-	-	V
		$V_{CC} = 4.5 V$	3.15	-	-	V
		$V_{CC} = 6.0 V$	4.2	-	-	V
VIL	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.5	V
		V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
√ _{он}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_0 = -20 \ \mu A; \ V_{CC} = 2.0 \ V$	1.9	-	-	V
		$I_{O} = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ V$	4.4	-	-	V
		$I_{O} = -20 \ \mu\text{A}; \ V_{CC} = 6.0 \ V$	5.9	-	-	V
		$I_0 = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.84	-	-	V
		$I_0 = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.34	-	-	V

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{OL}	LOW-level output voltage	$V_I = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	-	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	-	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	-	0.1	V
		I_{O} = 6.0 mA; V_{CC} = 4.5 V	-	-	0.33	V
		I_{O} = 7.8 mA; V_{CC} = 6.0 V	-	-	0.33	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0$ V;	-	-	±1.0	μΑ
oz	OFF-state output current	$V_{I} = V_{IH}$ or V_{IL} ; $V_{O} = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±5.0	μΑ
l _{cc}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0$ V	-	-	80	μΑ
T _{amb} = –	40 °C to +125 °C					
VIH	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.5	V
		V _{CC} = 4.5 V	-	-	1.35	V
		$V_{CC} = 6.0 V$	-	-	1.8	V
V _{он}	HIGH-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_{O} = -20 \ \mu\text{A}; \ V_{CC} = 2.0 \ \text{V}$	1.9	-	-	V
		$I_{O} = -20 \ \mu\text{A}; \ V_{CC} = 4.5 \ V$	4.4	-	-	V
		$I_{O} = -20 \ \mu\text{A}; \ V_{CC} = 6.0 \ V$	5.9	-	-	V
		$I_{O} = -6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.7	-	-	V
		$I_{O} = -7.8 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.2	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{IH} \text{ or } V_{IL}$				
		$I_0 = 20 \ \mu A; \ V_{CC} = 2.0 \ V$	-	-	0.1	V
		$I_{O} = 20 \ \mu A; \ V_{CC} = 4.5 \ V$	-	-	0.1	V
		$I_0 = 20 \ \mu A; \ V_{CC} = 6.0 \ V$	-	-	0.1	V
		$I_0 = 6.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.4	V
		I _O = 7.8 mA; V _{CC} = 6.0 V	-	-	0.4	V
I	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 6.0 V$	-	-	±1.0	μΑ
OZ	OFF-state output current	$V_{I} = V_{IH}$ or V_{IL} ; $V_{O} = V_{CC}$ or GND; $V_{CC} = 6.0$ V	-	-	±10.0	μA
СС	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0$ V	-	-	160	μA

Table 6. Static characteristics 74HC366 ... continued

Static characteristics 74HCT366 Table 7.

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbo	ol Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} =	25 °C					
V _{IH}	HIGH-level input voltage	V_{CC} = 4.5 V to 5.5 V	2.0	1.6	-	V
V_{IL}	LOW-level input voltage	V_{CC} = 4.5 V to 5.5 V	-	1.2	0.8	V
V _{OH}	HIGH-level output	$V_I = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
	voltage	$I_O = -20 \ \mu A$	4.4	4.5	-	V
		$I_{O} = -6.0 \text{ mA}$	3.98	4.32	-	V
74HC_HCT36	6	All information provided in this document is subject to legal disclaimers.		© NXP I	3.V. 2012. All	rights reserved
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Hex buffer/line driver; 3-state; inverting

Symbol	Parameter	Conditions	Min	Тур	Max	Uni
V _{OL}	LOW-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
	voltage	I _O = 20 μA	-	0	0.1	V
		I _O = 6.0 mA	-	0.16	0.26	V
l	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±0.1	μΑ
l _{oz}	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND per input pin; other inputs at GND or V_{CC} ; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	±0.5	μA
СС	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 5.5$ V	-	-	8.0	μΑ
Δl _{CC}	additional supply current	$V_I = V_{CC} - 2.1$ V; other inputs at V_{CC} or GND; $I_O = 0$ A				
		pins nA	-	100	360	μA
		pin OE1	-	100	360	μA
		pin OE2	-	90	320	μA
Cı	input capacitance		-	3.5	-	pF
T _{amb} = –	40 °C to +85 °C					
ViH	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V} \text{ to } 5.5 \text{ V}$	2.0	-	-	V
VIL	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	-	0.8	V
V _{он}	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
	voltage	I _O = -20 μA	4.4	-	-	V
		I _O = -6.0 mA	3.84	-	-	V
V _{OL}	LOW-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
	voltage	I _O = 20 μA	-	-	0.1	V
		I _O = 6.0 mA	-	-	0.33	V
1	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±1.0	μA
oz	OFF-state output current	$V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND per input pin; other inputs at GND or V_{CC} ; $I_O = 0$ A; $V_{CC} = 5.5$ V			±5.0	μA
СС	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	80	μA
۵lcc	additional supply current	$V_I = V_{CC} - 2.1$ V; other inputs at V_{CC} or GND; $I_O = 0$ A				
		pins nA	-	-	450	μA
		pin OE1	-	-	450	μA
		pin OE2	-	-	400	μA
T _{amb} = –	40 °C to +125 °C					
V _{IH}	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	2.0	-	-	V
V _{IL}	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	-	-	0.8	V
V _{он}	HIGH-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
	voltage	I _O = -20 μA	4.4	-	-	V
		$I_{O} = -6.0 \text{ mA}$	3.7	-	-	V
V _{OL}	LOW-level output	$V_{I} = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$				
	voltage	I _O = 20 μA	-	-	0.1	V
		$I_0 = 6.0 \text{ mA}$	-	-	0.4	V
	input leakage current	$V_{I} = V_{CC}$ or GND; $V_{CC} = 5.5 V$	-	-	±1.0	μA
I _{oz}	OFF-state output current		-	-	±10.0	μA

Static characteristics 74HCT366 ... continued Table 7.

d to CND (around 01/)

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Table 7. Static characteristics 74HCT366 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5$ V	-	-	160	μΑ
ΔI_{CC}	CC additional supply current	V_{I} = V_{CC} – 2.1 V; other inputs at V_{CC} or GND; I_{O} = 0 A				
		pins nA	-	-	490	μA
		pin OE1	-	-	490	μΑ
		pin OE2	-	-	441	μA

10. Dynamic characteristics

Table 8. Dynamic characteristics 74HC366

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; see test circuit Figure 8.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C					
t _{pd}	propagation delay	nA to nY; see Figure 6	<u>[1]</u>			
		$V_{CC} = 2.0 V$	-	33	100	ns
		$V_{CC} = 4.5 V$	-	12	20	ns
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$	-	10	-	ns
		$V_{CC} = 6.0 V$	-	10	17	ns
t _{en}	enable time	OEn to nY; see Figure 7	<u>[2]</u>			
		$V_{CC} = 2.0 V$	-	44	150	ns
		$V_{CC} = 4.5 V$	-	16	30	ns
		$V_{CC} = 6.0 V$	-	13	26	ns
t _{dis}	disable time	OEn to nY; see Figure 7	<u>[3]</u>			
		$V_{CC} = 2.0 V$	-	55	150	ns
		$V_{CC} = 4.5 V$	-	20	30	ns
		$V_{CC} = 6.0 V$	-	16	26	ns
t _t	transition time	see Figure 6	<u>[4]</u>			
		$V_{CC} = 2.0 V$	-	14	60	ns
		$V_{CC} = 4.5 V$	-	5	12	ns
		$V_{CC} = 6.0 V$	-	4	10	ns
C _{PD}	power dissipation capacitance	per buffer; V_I = GND to V_{CC}	<u>[5]</u> _	30	-	pF
T _{amb} = -	40 °C to +85 °C					
t _{pd}	propagation delay	nA to nY; see Figure 6	<u>[1]</u>			
		$V_{CC} = 2.0 V$	-	-	125	ns
		$V_{CC} = 4.5 V$	-	-	25	ns
		$V_{CC} = 6.0 V$	-	-	21	ns
t _{en}	enable time	OEn to nY; see Figure 7	[2]			
		$V_{CC} = 2.0 V$	-	-	190	ns
		$V_{CC} = 4.5 V$	-	-	38	ns
		$V_{CC} = 6.0 V$	-	-	33	ns

Hex buffer/line driver; 3-state; inverting

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t _{dis}	disable time	OEn to nY; see Figure 7	<u>[3]</u>			
		$V_{CC} = 2.0 V$	-	-	190	ns
		$V_{CC} = 4.5 V$	-	-	38	ns
		$V_{CC} = 6.0 V$	-	-	33	ns
tt	transition time	see <u>Figure 6</u>	<u>[4]</u>			
		$V_{CC} = 2.0 V$	-	-	75	ns
		$V_{CC} = 4.5 V$	-	-	15	ns
		$V_{CC} = 6.0 V$	-	-	13	ns
T _{amb} = -	40 °C to +125 °C					
t _{pd}	propagation delay	nA to nY; see <u>Figure 6</u>	<u>[1]</u>			
		$V_{CC} = 2.0 V$	-	-	150	ns
		$V_{CC} = 4.5 V$	-	-	30	ns
		$V_{CC} = 6.0 V$	-	-	26	ns
t _{en}	enable time	OEn to nY; see Figure 7	[2]			
		$V_{CC} = 2.0 V$	-	-	225	ns
		$V_{CC} = 4.5 V$	-	-	45	ns
		$V_{CC} = 6.0 V$	-	-	38	ns
t _{dis}	disable time	OEn to nY; see Figure 7	[3]			
		$V_{CC} = 2.0 V$	-	-	225	ns
		$V_{CC} = 4.5 V$	-	-	45	ns
		$V_{CC} = 6.0 V$	-	-	38	ns
t _t	transition time	see Figure 6	<u>[4]</u>			
		$V_{CC} = 2.0 V$	-	-	90	ns
		$V_{CC} = 4.5 V$	-	-	18	ns
		$V_{CC} = 6.0 V$	-	-	15	ns

Dynamic characteristics 74HC366 ... continued Table 8.

[1] t_{pd} is the same as t_{PHL} and t_{PLH} .

[2] t_{en} is the same as t_{PZH} and t_{PZL} .

[3] t_{dis} is the same as t_{PHZ} and t_{PLZ} .

- [4] t_t is the same as t_{THL} and t_{TLH} .
- [5] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$ where: f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$

Hex buffer/line driver; 3-state; inverting

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	5 °C					
t _{pd}	propagation delay	nA to nY; see Figure 6	<u>[1]</u>			
		$V_{CC} = 4.5 V$	-	13	24	ns
		$V_{CC} = 5 \text{ V}; \text{ C}_{L} = 15 \text{ pF}$	-	11	-	ns
t _{en}	enable time	$\overline{\text{OEn}}$ to nY; V _{CC} = 4.5 V; see Figure 7	[2] _	16	35	ns
t _{dis}	disable time	$\overline{\text{OEn}}$ to nY; V _{CC} = 4.5 V; see Figure 7	<u>[3]</u> _	20	35	ns
t _t	transition time	V _{CC} = 4.5 V; see <u>Figure 6</u>	<u>[4]</u> _	5	12	ns
C _{PD}	power dissipation capacitance	per buffer; $V_I = GND$ to $(V_{CC} - 1.5 V)$	<u>[5]</u> _	30	-	pF
T _{amb} = -4	40 °C to +85 °C					
t _{pd}	propagation delay	nA to nY; V_{CC} = 4.5 V; see <u>Figure 6</u>	<u>[1]</u> -	-	30	ns
t _{en}	enable time	$\overline{\text{OEn}}$ to nY; V _{CC} = 4.5 V; see Figure 7	[2] _	-	44	ns
t _{dis}	disable time	$\overline{\text{OEn}}$ to nY; V _{CC} = 4.5 V; see Figure 7	[3] _	-	44	ns
t _t	transition time	V_{CC} = 4.5 V; see <u>Figure 6</u>	[4] _	-	15	ns
T _{amb} = -4	40 °C to +125 °C					
t _{pd}	propagation delay	nA to nY; V_{CC} = 4.5 V; see <u>Figure 6</u>	<u>[1]</u> _	-	36	ns
t _{en}	enable time	$\overline{\text{OEn}}$ to nY; V _{CC} = 4.5 V; see Figure 7	[2] _	-	53	ns
t _{dis}	disable time	$\overline{\text{OEn}}$ to nY; V _{CC} = 4.5 V; see Figure 7	[3] _	-	53	ns
t _t	transition time	$V_{CC} = 4.5 V$; see Figure 6	[4] _	-	18	ns

Table 9. Dynamic characteristics 74HCT366

Voltages are referenced to GND (ground = 0 V); $C_L = 50 \text{ pF}$ unless otherwise specified; see test circuit Figure 8.

[1] t_{pd} is the same as t_{PHL} and t_{PLH} .

[2] t_{en} is the same as t_{PZH} and t_{PZL} .

[3] t_{dis} is the same as t_{PHZ} and t_{PLZ} .

[4] t_t is the same as t_{THL} and t_{TLH} .

[5] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 P_{D} = $C_{PD} \times V_{CC}{}^2 \times f_i \times N$ + $\sum (C_L \times V_{CC}{}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

 $f_o =$ output frequency in MHz;

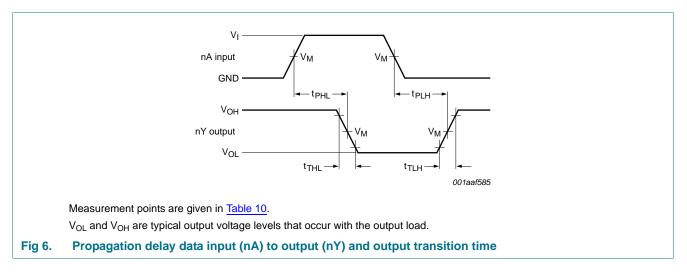
 C_L = output load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching; $\Sigma(C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$

Hex buffer/line driver; 3-state; inverting

11. Waveforms



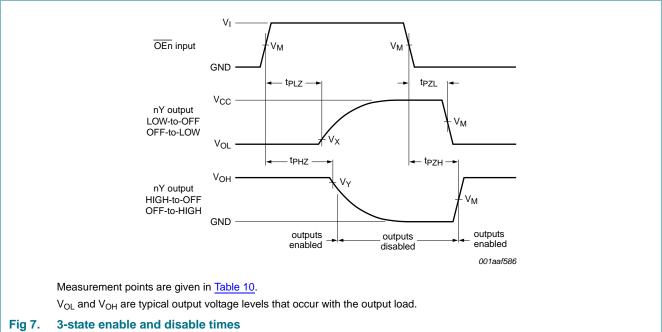


Table 10. Measurement points

Туре	Input	Output		
	V _M	V _M	V _X	V _Y
74HC366	0.5V _{CC}	0.5V _{CC}	$0.1 \times V_{CC}$	$0.9 \times V_{CC}$
74HCT366	1.3 V	1.3 V	$0.1\times V_{CC}$	$0.9\times V_{CC}$

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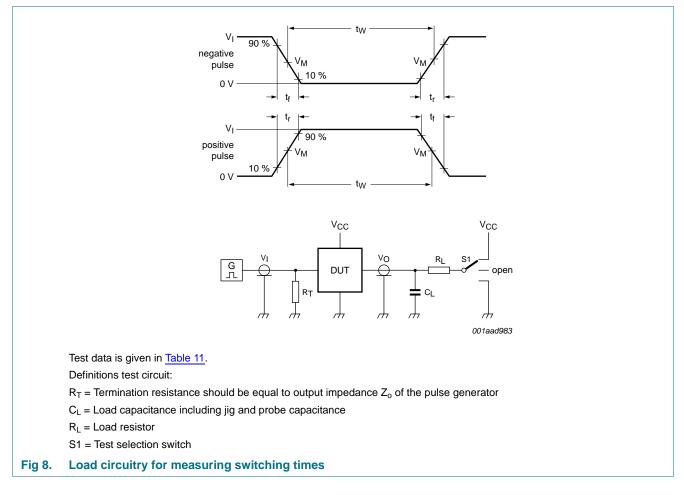


Table 11. Test data

Туре	Input		Load		S1 position		
	VI	t _r , t _f	CL	RL	t _{PHL} , t _{PLH}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
74HC366	V _{CC}	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}
74HCT366	3 V	6 ns	15 pF, 50 pF	1 kΩ	open	GND	V _{CC}

Hex buffer/line driver; 3-state; inverting

12. Package outline

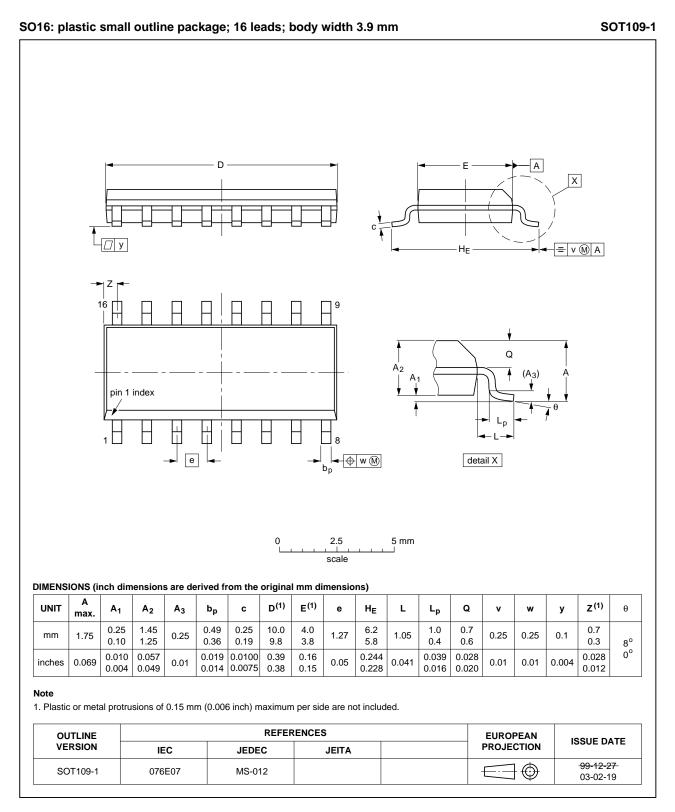


Fig 9. Package outline SOT109-1 (SO16)

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Hex buffer/line driver; 3-state; inverting

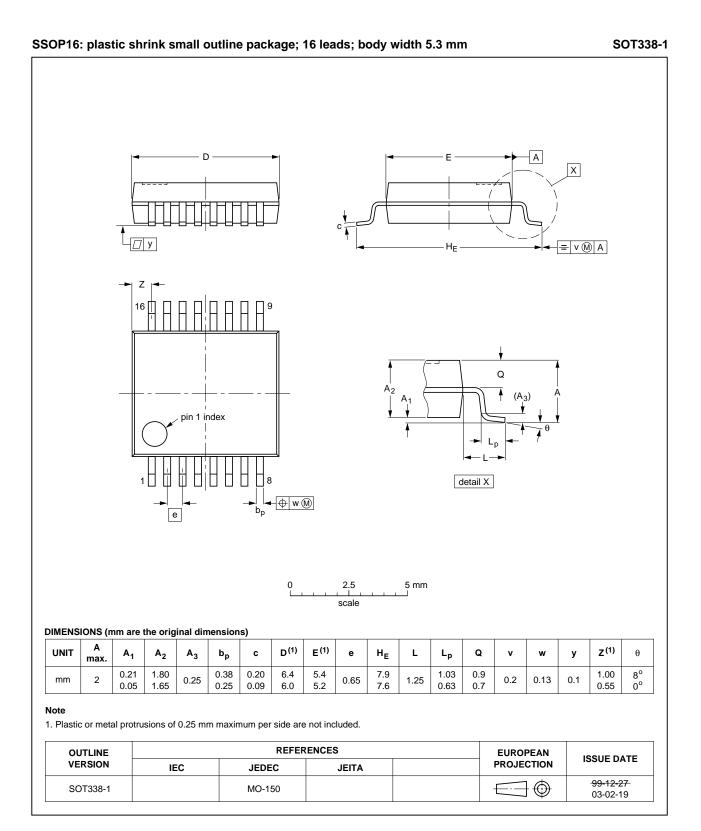


Fig 10. Package outline SOT338-1 (SSOP16)

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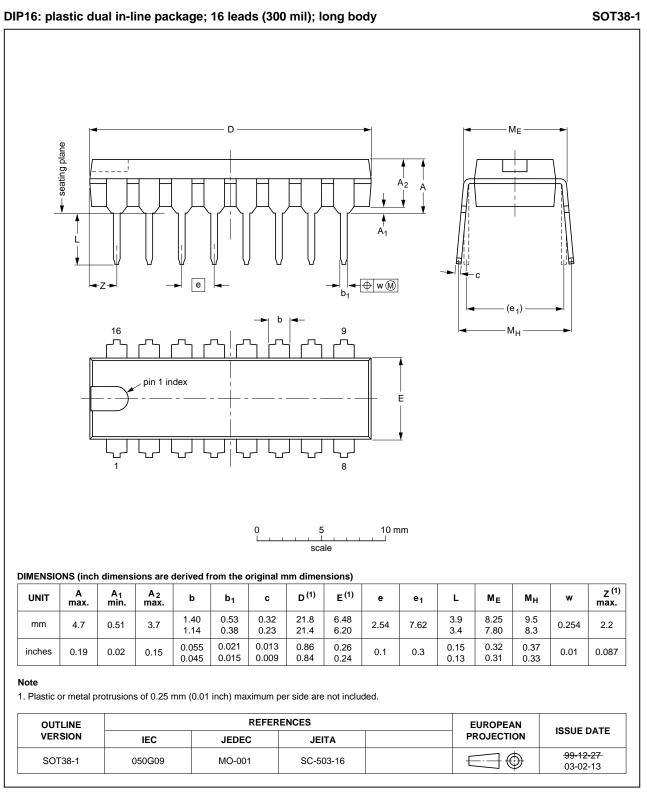


Fig 11. Package outline SOT38-1 (DIP16)

Hex buffer/line driver; 3-state; inverting

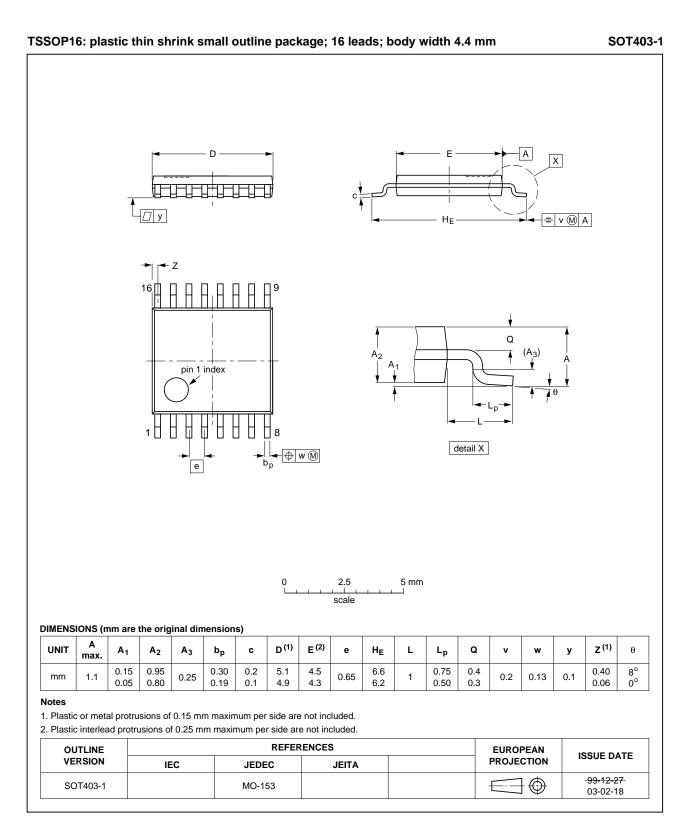


Fig 12. Package outline SOT403-1 (TSSOP16)

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Hex buffer/line driver; 3-state; inverting

13. Abbreviations

Table 12. Abbreviations				
Acronym	Description			
CMOS	Complementary Metal Oxide Semiconductor			
DUT	Device Under Test			
ESD	ElectroStatic Discharge			
HBM	Human Body Model			
LSTTL	Low-power Schottky Transistor-Transistor Logic			
MM	Machine Model			

14. Revision history

Table 13. Revision histo	ory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC_HCT366 v.4	20120904	Product data sheet	-	74HC_HCT366 v.3
Modifications:	 Legal pages 	updated.		
74HC_HCT366 v.3	20061121	Product data sheet	-	74HC_HCT366_CNV v.2
74HC_HCT366_CNV v.2	19901201	Product specification	-	-

Hex buffer/line driver; 3-state; inverting

15. Legal information

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Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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74HC_HCT366

Product data sheet

Hex buffer/line driver; 3-state; inverting

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Hex buffer/line driver; 3-state; inverting

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